

-20V Dual P-Channel HEXFET Power MOSFET in a SO-8 package; Similar to IRF7324TR with Lead Free Packaging on Tape and Reel

| | |
|---------------|---|
| Manufacturers | Infineon Technologies Corporation |
| Package/Case | SOP-8 |
| Product Type | Transistors |
| RoHS | Green |
| Lifecycle | |



Images are for reference only

Please submit RFQ for IRF7324TRPBF or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

New trench HEXFET® Power MOSFETs from International Rectifier utilize advanced processing techniques to achieve extremely low on-resistance per silicon area. This benefit, combined with the ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in battery and load management applications.

- Trench Technology
- Ultra Low On-Resistance
- Dual P-Channel MOSFET
- Low Profile (<1.1mm)
- Available in Tape & Reel
- 2.5V Rated

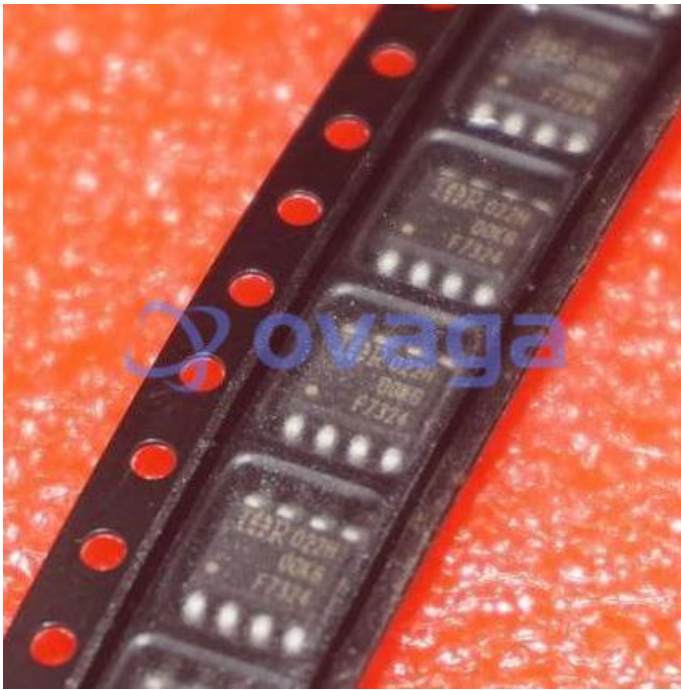
Features

RoHS Compliant

Low RDS(on)

Low Profile (less than 1.1 mm)

Dual P-Channel MOSFET

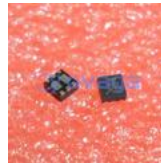


Related Products



[IRLTS6342TRPBF](#)

Infineon Technologies Corporation
TSOP-6



[IRLHS6376TRPBF](#)

Infineon Technologies Corporation
PQFN2x2DD



[IRF9310PBF](#)

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SOIC-8



[IRFH9310TRPBF](#)

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PQFN-8



[IRF9358TRPBF](#)

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SOP-8



[IRFB7430PBF](#)

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TO-220



[IRFB3307ZPBF](#)

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TO-220AB



[IRF7351TRPBF](#)

Infineon Technologies Corporation
SOIC-8